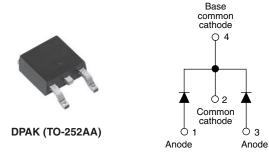
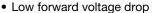


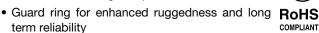
High Performance Schottky Rectifier, 2 x 6 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 6 A				
V_{R}	30 V				
V _F at I _F	0.37 V				
I _{RM}	58 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	10 mJ				
Package	DPAK (TO-252AA)				
Circuit configuration	Common cathode				

FEATURES







- Popular D-PAK outline
- · Center tap configuration
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-12CWQ03FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	12	Α				
V _{RRM}		30	V				
I _{FSM}	$t_p = 5 \mu s sine$	320	Α				
V _F	6 A _{pk} , T _J = 125 °C (per leg)	0.37	V				
T _J	Range	-55 to +150	°C				

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-12CWQ03FN-M3	UNITS		
Maximum DC reverse voltage	V _R	30	V		
Maximum working peak reverse voltage	V_{RWM}	30	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average forward current, see fig. 5 per device		_	50 % duty cycle at T _C = 135 °C, rectangular waveform		6	А	
		I _{F(AV)}			12		
Maximum peak one cycle nor	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	320	А	
surge current per leg, see fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	130		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 2.0 A, L = 5 mH		10	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		2.0	Α	



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		6 A	- T _{.1} = 25 °C	0.47		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	12 A	1j=25 0	0.55	v	
See fig. 1	V FM \''	6 A	T _{.1} = 125 °C	0.37		
		12 A	1) = 125 0	0.49		
Maximum reverse	. (1)	T _J = 25 °C	·			
leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	$T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_R$		58	mA	
Threshold voltage	V _{F(TO)}	T. T. manimum		0.196	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum	21.66	m $Ω$		
Typical junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	590	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 n	nm from package body	5.0	nH	

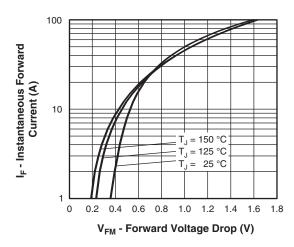
Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage ter	nperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C		
Maximum thermal resistance, junction to case	per leg	R _{thJC}	DC operation See fig. 4	3.0	°C/W		
	per device			1.5			
Approximate weight				0.3	g		
				0.01	OZ.		
Marking device			Case style DPAK (TO-252AA)	12CW	Q03FN		

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



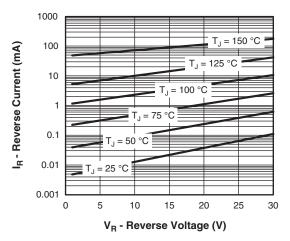


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

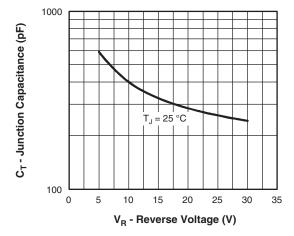


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

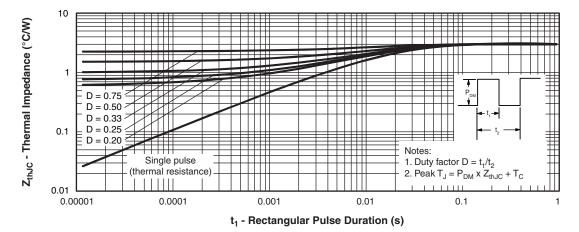
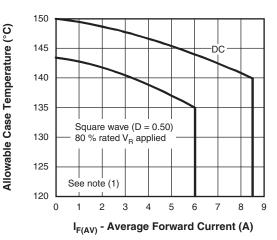


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

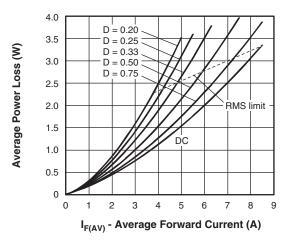


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

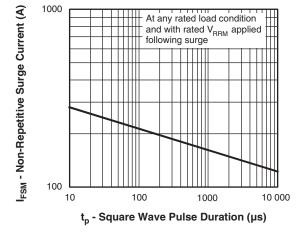


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

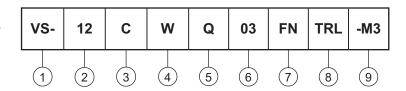
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (12 A)

Center tap configuration

4 - Package identifier:

W = DPAK

5 - Schottky "Q" series

6 - Voltage rating (03 = 30 V)

7 - FN = TO-252AA

8 - • None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-12CWQ03FN-M3	75	3000	Antistatic plastic tube			
VS-12CWQ03FNTR-M3	2000	2000	13" diameter reel			
VS-12CWQ03FNTRL-M3	3000	3000	13" diameter reel			
VS-12CWQ03FNTRR-M3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95627</u>					
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				
SPICE model	www.vishay.com/doc?96476				



D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	1	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STINIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573
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